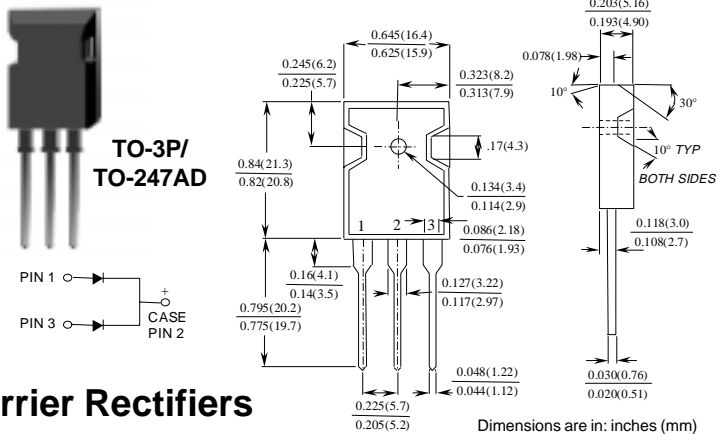


# MBR3035PT - MBR3060PT

## Features

- Low power loss, high efficiency.
- High surge capacity.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current capacity, low forward voltage drop.
- Guard ring for over voltage protection.



## 30 Ampere Schottky Barrier Rectifiers

### Absolute Maximum Ratings\*

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value	Units
$I_O$	Average Rectified Current	30	A
$i_{f(\text{repetitive})}$	Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 KHz) @ $T_A = 130^\circ\text{C}$	30	A
$i_{f(\text{surge})}$	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	200	A
$P_D$	Total Device Dissipation Derate above $25^\circ\text{C}$	3.0 25	W mW/ $^\circ\text{C}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	1.4	$^\circ\text{C}/\text{W}$
$T_{stg}$	Storage Temperature Range	-65 to +175	$^\circ\text{C}$
$T_J$	Operating Junction Temperature	-65 to +150	$^\circ\text{C}$

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise noted

Parameter	Device				Units
	3035PT	3045PT	3050PT	3060PT	
Peak Repetitive Reverse Voltage	35	45	50	60	V
Maximum RMS Voltage	24	31	35	42	V
DC Reverse Voltage (Rated $V_R$ )	35	45	50	60	V
Voltage Rate of Change (Rated $V_R$ )	10,000				V/ $\mu\text{s}$
Maximum Reverse Current @ rated $V_R$	$T_A = 25^\circ\text{C}$	1.0		5.0	mA
	$T_A = 125^\circ\text{C}$	60		100	mA
Maximum Forward Voltage $I_F = 20\text{ A}$ , $T_C = 25^\circ\text{C}$ $I_F = 20\text{ A}$ , $T_C = 125^\circ\text{C}$ $I_F = 30\text{ A}$ , $T_C = 25^\circ\text{C}$ $I_F = 30\text{ A}$ , $T_C = 125^\circ\text{C}$		-	0.75		V
		0.60	0.65		V
		0.76	-		V
		0.72	-		V
Peak Repetitive Reverse Surge Current 2.0 $\mu\text{s}$ Pulsu Width, $f = 1.0\text{ KHz}$		1.0		0.5	A

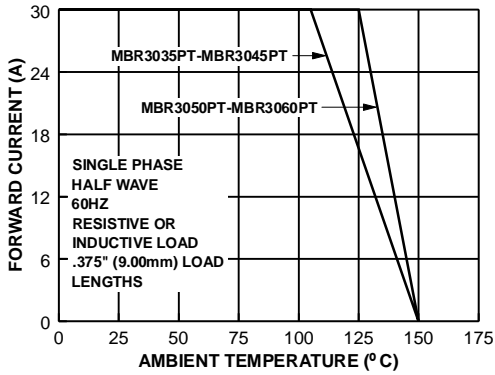
# Schottky Barrier Rectifier

(continued)

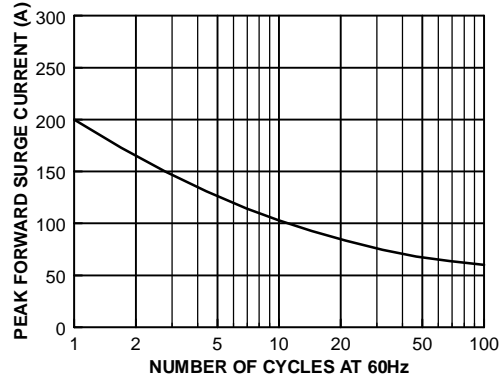
MBR3035PT - MBR3060PT

## Typical Characteristics

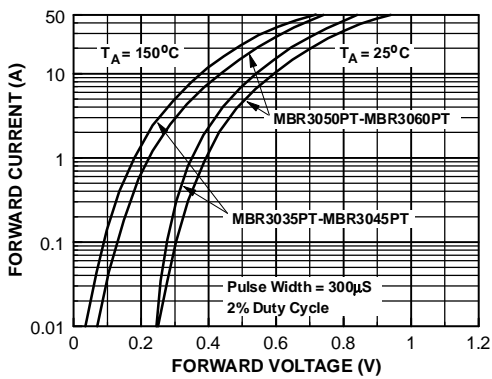
### Forward Current Derating Curve



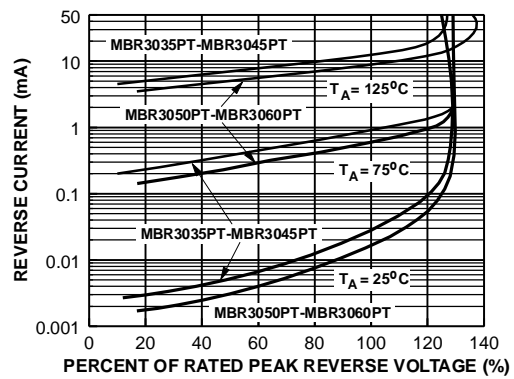
### Non-Repetitive Surge Current



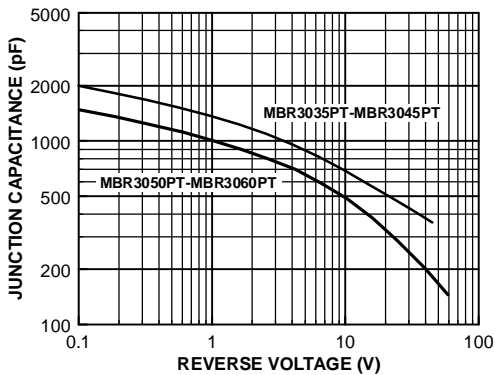
### Forward Characteristics



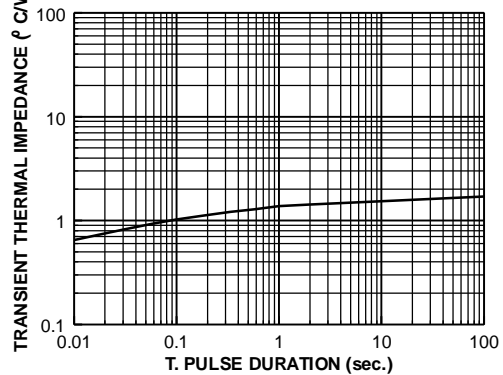
### Reverse Characteristics



### Typical Junction Capacitance



### Transient Thermal Impedance



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CROSSVOLT™	POP™
E <sup>2</sup> CMOS™	PowerTrench™
FACT™	QS™
FACT Quiet Series™	Quiet Series™
FAST®	SuperSOT™-3
FASTr™	SuperSOT™-6
GTO™	SuperSOT™-8
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### Definition of Terms

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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